						-	KE VISIO	SNC										
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А	Changes in accord	dance wi	ith N.O	.R. 596	62-R22	8-92.						92-0	8-11		M.A. FRYE			
В	Changes in accord												2-14		M.A. FRYE			
С	Changes in accord)8-16				FRYE	
D	Changes in accord												2-03			R. MONNIN		
E	Make changes to a Redrawn ro	Make changes to slew rate test as specified under TABLE I Redrawn ro					BLEIh	erein.				98-1	2-11			R. M	ИІИИС	
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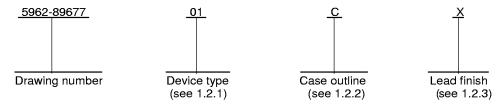
SHEET

1 OF

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1. SCOPE

- 1.1 <u>Scope</u>. This drawing describes device requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A.
 - 1.2 Part or Identifying Number (PIN). The complete PIN is as shown in the following example:



1.2.1 $\underline{\text{Device type(s)}}$. The device type(s) identify the circuit function as follows:

Device type	<u>Generic number</u>	<u>Circuit function</u>
01	LT1014A	Quad precision operational amplifier
02	LT1014	Quad precision operational amplifier

1.2.2 <u>Case outline(s)</u>. The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
С	GDIP1-T14 or CDIP2-T14	14	Dual-in-line
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
Χ	CDFP3-F14	14	Flat pack
2	CQCC1-N20	20	Square leadless chip carrier

- 1.2.3 Lead finish. The lead finish is as specified in MIL-PRF-38535, appendix A.
- 1.3 Absolute maximum ratings. 1/

Positive supply voltage (V+)	+22 V
Negative supply voltage (V-)	
Power dissipation (P _D)	500 mW <u>2</u> /
Differential input voltage	±30 V
Input voltage	
	5 V below negative supply voltage
Output short-circuit duration	Indefinite
Storage temperature range	65°C to +150°C
Lead temperature (soldering, 60 seconds):	
Cases C, D, and X	+300°C
Case 2	+260°C
Junction temperature (T _J)	65°C to +150°C
Thermal resistance, junction-to-case (θ _{JC})	See MIL-STD-1835
Thermal resistance, junction-to-ambient (θ_{JA}):	
Cases C and X	100°C/W
Case D	180°C/W
Case 2	65°C/W

^{1/} Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

 $[\]underline{2}$ / Must withstand the added P_D due to short circuit test; e.g., I_{OS} .

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1.4 Recommended operating conditions.

Positive supply voltage (V+)+15 V
Negative supply voltage (V-)-15 V
Ambient operating temperature range (T_A)....-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-973 - Configuration Management.

MIL-STD-1835 - Interface Standard For Microcircuit Case Outlines.

HANDBOOKS

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's).

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-PRF-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-PRF-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-PRF-38535 is required to identify when the QML flow option is used.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535, appendix A and herein.
 - 3.2.1 <u>Case outline(s)</u>. The case outline(s) shall be in accordance with 1.2.2 herein.
 - 3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions $-55^{\circ}C \le T_{A} \le +125^{\circ}C$ unless otherwise specified	Group A subgroups	Device type	Lir	nits	Unit
		·			Min	Max	
Input offset voltage 1/	Vos		1	01		±180	μV
			2,3			±350	_
			1	02		±300	
			2,3			±550	
Input offset current 1/	los		1	01		±0.8	nA
			2,3	1		±2.8	
			1	02		±1.5	
			2,3			±5	
Input bias current <u>1</u> /	I _B		1	01		±20	nA
			2,3	1		±30	
			1	02		±30	
			2,3			±45	
Input voltage range 1/2/	IVR		1	01	-15.0	+13.5	V
			2,3		-14.9	+13.0	
			1	02	-15.0	+13.5	
			2,3		-14.9	+13.0	
Common mode 1/	CMRR	V _{CM} = +13.5 V, -15.0 V	1	01	100		dB
rejection ratio		V _{CM} = +13.0 V, -14.9 V	2,3		96		
		V _{CM} = +13.5 V, -15.0 V	1	02	97		
		V _{CM} = +13.0 V, -14.9 V	2,3		94		
Power supply rejection 1/	PSRR	V+ = +2 V to +18 V,	1	01	103		dB
ratio		V- = -2 V to −18 V	2,3	1	100		
		V+ = +2 V to +18 V,	1	02	100		
		V- = -2 V to -18 V	2,3		97		
Output voltage swing 1/	V _{OUT}	$R_L \ge 2 k\Omega$	4	01	±13		٧
			5,6		±12		
			4	02	±12.5		
			5,6		±11.5		
Large signal voltage 1/	A _{VO}	$R_L \ge 2 \text{ k}\Omega, V_O = \pm 10 \text{ V}$	4	01	1.5		V/µV
gain			5,6		0.4		
			4	02	1.2		
			5,6		0.25		

See footnotes at end of table.

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 $\label{eq:table I.} \ \underline{\mbox{Electrical performance characteristics}} - \mbox{Continued}.$

Test	Symbol	Conditions $ -55^{\circ}C \leq T_{A} \leq +125^{\circ}C $ unless otherwise specified	Group A subgroups	Device type	Liı	mits	Unit
				"	Min	Max	1
Power supply current 1/	I _{SY}	No load each amplifier	1	01		0.5	mA
			2,3	1		0.6	1
			1	02		0.55	1
			2,3			0.70	
Power dissipation 1/	P _D	No load each amplifier,	1	01		15	mW
		guaranteed by I _{SY} limits	2,3			18	
			1	02		16.5	1
			2,3			21	
Channel separation 1/3/	cs	T _A = +25°C	7	01	123		dB
			7	02	120		1
Input noise voltage 1/3/	E _N	f = 0.1 Hz to 10 Hz	4	All		1.1	μV _{P-P}
Input noise voltage 1/3/	E _{ND}	f _O = 10 Hz	4	All		40	nV/√Hz
density		f _O = 1 kHz	4	1		30	1
Output short circuit 1/3/	I _{SC-}	T _A = +25°C	1	All		-60	mA
current	I _{SC+}		1			60	1
Input resistance 1/3/	R _{IN}		1	01	100		МΩ
differential mode			1	02	70		1
Slew rate <u>1</u> / <u>3</u> /	SR		4	All	0.2		V/µs
Input offset voltage 1/	ΔV _{OS}	Guaranteed by V _{OS} limits	1	01		±360	μV
match			2,3	1		±700	1
			1	02		±600	
			2,3			±1100]
Input offset voltage 4/	V _{OS}		1	01		±280	μV
		V _{CM} = 0.1 V	2,3	01		±480]
			2	01		±960]
			3	01		±480]
			1	02		±450]
		V _{CM} = 0.1 V	2,3	02		±750]
			2	02		±1500]
			3	02		±750	

See footnotes at end of table.

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 $\label{eq:table I.} \ \underline{\mbox{Electrical performance characteristics}} - \mbox{Continued}.$

	1	Conditions					
Test	Symbol	-55°C \leq T _A \leq +125°C unless otherwise specified	Group A subgroups	Device type	Lir	nits	Unit
					Min	Max	
Input offset current 4/	los		1	01		1.3	nA
			2,3			7.0	
			1	02		2.0	
			2,3	1		10.0	
Input bias current <u>4</u> /	I _B		1	01		35	nA
			2,3			90	
			1	02		50	
			2,3			120	
Input voltage range 4/	IVR		1	01	0	3.5	٧
			1	02	0	3.5	
Output voltage swing 4/	V _{OUT}	No load, output low	4	All		25	mV
		No load, output high	4	All	4		٧
		Output low, sink = 1 mA	4	All		350	mV
		600 Ω load, output low	4	All		10	
		600 Ω load, output high	4	All	3.4		٧
		600 Ω load, output low	5,6	01		15	mV
			5,6	02		18	
		600 Ω load, output high	5,6	01	3.2		٧
			5,6	02	3.1		
Supply current 4/	I _{SY}	Per amplifier	1	01		.45	mA
			2,3	1		.55	
			1	02		.5	
			2,3			.65	
Large signal voltage 3/4/	A _{VO}	$R_L = 2 \text{ k}\Omega \text{ to GND},$	4	All	0.5		V/µV
gain		V _O = 0.1 V to 3.4 V					
Power dissipation 4/	P _D	No load each amplifier,	1	01		2.25	mW
		guaranteed by I _{SY} limits	2,3	1		2.75	1
			1	02		2.5	
			2,3	1		3.25	1

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $ -55^{\circ}C \leq T_A \leq +125^{\circ}C $ unless otherwise specified	Group A subgroups	Device type	Limits		Unit
					Min	Max	
Power supply 4/	PSRR	V+ = +2 V to +18 V	1	01	103		dB
rejection ratio		V- = -2 V to −18 V	2,3		100		
		V+ = +2 V to +18 V	1	02	100		
		V- = -2 V to −18 V	2,3		97		

- 1/V Unless otherwise specified, $V = \pm 15 V$ and $V_{CM} = 0 V$.
- 2/ IVR is guaranteed by CMRR test.
- 3/ If not tested, shall be guaranteed to the limits specified in table I herein..
- 4/ Unless otherwise specified, $V_{+} = +5 \text{ V}$, $V_{-} = 0 \text{ V}$, $V_{CM} = 0 \text{ V}$, and $V_{OUT} = 1.4 \text{ V}$.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full ambient operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table I.
- 3.5 <u>Marking</u>. Marking shall be in accordance with MIL-PRF-38535, appendix A. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103 (see 6.6 herein). For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device.
- 3.6 <u>Certificate of compliance</u>. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-PRF-38535, appendix A and the requirements herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change</u>. Notification of change to DSCC-VA shall be required in accordance with MIL-PRF-38535, appendix A.
- 3.9 <u>Verification and review</u>. DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

STANDARD MICROCIRCUIT DRAWING

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Doving types	01 and 02	02	02	01 and 02
Device types			X	
Case outlines	С	D	, ,	2
Terminal number		Terminal		
1	OUT A	OUT A	OUT A	NC
2	-IN A	-IN A	-IN A	OUT A
3	+IN A	+IN A	+IN A	-IN A
4	V+	V+	V+	+IN A
5	+IN B	+IN B	+IN B	NC
6	-IN B	-IN B	-IN B	V+
7	OUT B	OUT B	OUT B	NC
8	OUT C	OUT C	OUT C	+IN B
9	-IN C	-IN C	-IN C	-IN B
10	+IN C	+IN C	+IN C	OUT B
11	V-	V-	V-	NC
12	+IN D	+IN D	+IN D	OUT C
13	-IN D	-IN D	-IN D	-IN C
14	OUT D	OUT D	OUT D	+IN C
15				NC
16				V-
17				NC
18				+IN D
19				-IN D
20				OUT D

FIGURE 1. <u>Terminal connections</u>.

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4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
 - (2) $T_A = +125^{\circ} C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 8, 9, 10, and 11 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) $T_A = +125^{\circ} C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
 - 5. PACKAGING
 - 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535, appendix A.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (in accordance with MIL-STD-883, method 5005, table I)
Interim electrical parameters (method 5004)	1
Final electrical test parameters (method 5004)	1*,2,3,4,5,6
Group A test requirements (method 5005)	1,2,3,4,5,6,7**
Groups C and D end-point electrical parameters (method 5005)	1

- * PDA applies to subgroup 1.
- ** Subgroup 7, if not tested, shall be guaranteed to the limits specified in table I.

6. NOTES

- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.2 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.
- 6.4 <u>Record of users</u>. Military and industrial users shall inform Defense Supply Center Columbus when a system application requires configuration control and the applicable SMD. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0525.
- 6.5 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0674.
- 6.6 <u>Approved sources of supply</u>. Approved sources of supply are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 98-12-11

Approved sources of supply for SMD 5962-89677 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-8967701CA	01295	LT1014AMJB
	64155	LT1014AMJ/883
5962-89677012A	01295	LT1014AMFKB
5962-8967702CA	01295	LT1014MJB
	64155	LT1014MJ/883
5962-8967702DA	<u>3</u> /	LT1014MW/883
5962-8967702XA	64155	LT1014MW/883
5962-89677022A	01295	LT1014MFKB

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGE <u>number</u>	Vendor name <u>and address</u>
1295	Texas Instruments, Incorporated 13500 N. Central Expressway P.O. Box 655303 Dallas, TX 75265 Point of contact 6412 Highway 75 South Sherman, TX 75090-0084
64155	Linear Technology Corporation 1630 McCarthy Boulevard Milpitas, CA 95035-7487

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.